# Triacs sensitive gate

# BT138B series E

MAX.

800E

800

12

95

UNIT

V

А

А

# GENERAL DESCRIPTION

Passivated, sensitive gate triacs in a plastic envelope suitable for surface mounting, intended for use in general purpose bidirectional switching and phase control applications, where high sensitivity is required in all four quadrants.

#### **PINNING - SOT404**

SYMBOL

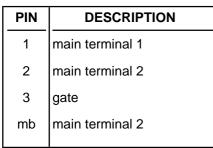
 $V_{\text{DRM}}$ 

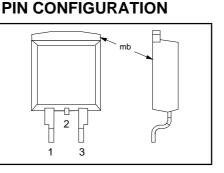
I<sub>T(RMS)</sub>

I<sub>TSM</sub>

### SYMBOL

BT138B-





QUICK REFERENCE DATA

PARAMETER

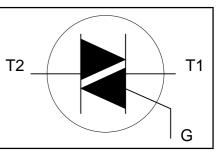
voltages

current

Repetitive peak off-state

Non-repetitive peak on-state

RMS on-state current



MAX.

600E

600

12

95

### LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.		UNIT
V <sub>DRM</sub>	Repetitive peak off-state voltages		-	<b>-600</b> 600 <sup>1</sup>	<b>-800</b> 800	V
I <sub>T(RMS)</sub> I <sub>TSM</sub>	RMS on-state current Non-repetitive peak on-state current	full sine wave; $T_{mb} \le 99 \degree C$ full sine wave; $T_j = 25 \degree C$ prior to surge	-	12		A
		t = 20  ms	-		5	A
121	12. for for inc	t = 16.7  ms	-		)5	A A <sup>2</sup> s
l²t dl <sub>⊤</sub> /dt	I <sup>2</sup> t for fusing Repetitive rate of rise of on-state current after	t = 10 ms $I_{TM} = 20 \text{ A}; I_G = 0.2 \text{ A};$ $dI_G/dt = 0.2 \text{ A}/\mu \text{s}$	-	4	5	A⁻s
	triggering	T2+ G+	-		0	A/μs
		T2+ G-	-		0	A/μs
		T2- G-	-		0	A/μs
		T2- G+	-		0	A/µs
I <sub>GM</sub> V <sub>GM</sub>	Peak gate current		-	4	2 5 5	A
V <sub>GM</sub>	Peak gate voltage		-		2	V
P <sub>GM</sub>	Peak gate power	aver any 20 ma pariod	-			W
$\begin{array}{c} P_{G(AV)}^{CM} \\ T_{stg} \\ T_{j} \end{array}$	Average gate power Storage temperature Operating junction temperature	over any 20 ms period	-40 -	15	.5 50 25	°℃ ℃

<sup>1</sup> Although not recommended, off-state voltages up to 800V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 15  $A/\mu s$ .

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## THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R <sub>th j-mb</sub> R <sub>th j-a</sub>	Thermal resistance junction to mounting base Thermal resistance junction to ambient	full cycle half cycle minimum footprint, FR4 board	-	- - 55	1.5 2.0 -	K/W K/W K/W

# STATIC CHARACTERISTICS

 $T_i = 25$  °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I <sub>GT</sub>	Gate trigger current	$V_{\rm D} = 12 \text{ V}; I_{\rm T} = 0.1 \text{ A}$				
01		T2+ G-	·   -	2.5	10	mA
		T2+ G-	-	4.0	10	mA
		T2- G-	-	5.0	10	mA
		T2- G+	-	11	25	mA
l I <sub>L</sub>	Latching current	$V_{\rm D} = 12 \text{ V}; I_{\rm GT} = 0.1 \text{ A}$				
		T2+ G-	·   -	3.2	30	mA
		T2+ G-	-	16	40	mA
		T2- G-	-	4.0	30	mA
		T2- G+	-	5.5	40	mA
I <sub>H</sub>	Holding current	$V_{\rm D} = 12 \text{ V}; I_{\rm GT} = 0.1 \text{ A}$	-	4.0	30	mA
I <sub>H</sub> V <sub>T</sub> V <sub>GT</sub>	On-state voltage	$I_{T} = 15 \text{ A}$	-	1.4	1.65	V
V <sub>GT</sub>	Gate trigger voltage	$V_{\rm D} = 12 \text{ V}; I_{\rm T} = 0.1 \text{ A}$	-	0.7	1.5	V
-	-	$V_{\rm D} = 400 \text{ V}; I_{\rm T} = 0.1 \text{ A}; T_{\rm i} = 125 \text{ °C}$	0.25	0.4	-	V
I <sub>D</sub>	Off-state leakage current	$V_{D} = 12 V; I_{T} = 0.1 A$ $V_{D} = 400 V; I_{T} = 0.1 A; T_{j} = 125 °C$ $V_{D} = V_{DRM(max)}; T_{j} = 125 °C$	-	0.1	0.5	mA

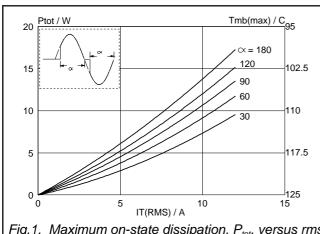
### **DYNAMIC CHARACTERISTICS**

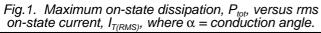
 $T_i = 25$  °C unless otherwise stated

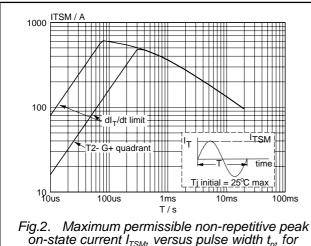
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
dV <sub>D</sub> /dt	Critical rate of rise of off-state voltage	$V_{DM} = 67\% V_{DRM(max)}; T_j = 125 °C;$ exponential waveform; gate open circuit	-	50	-	V/µs
t <sub>gt</sub>		$I_{TM} = 16 \text{ A}; V_D = V_{DRM(max)}; I_G = 0.1 \text{ A}; dI_G/dt = 5 \text{ A/}\mu\text{s}$	-	2	-	μs

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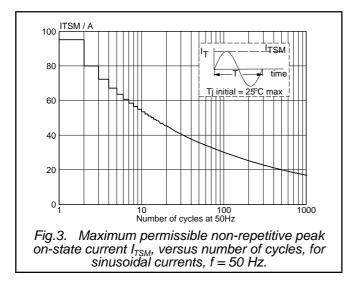
# Triacs sensitive gate

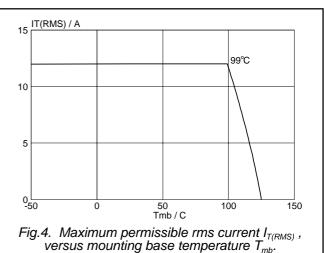


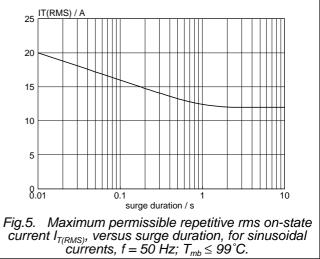


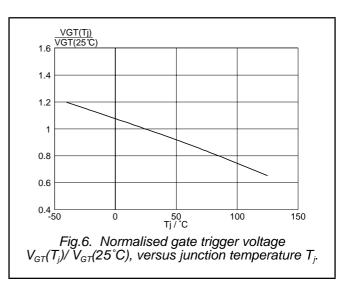


on-state current  $I_{TSM}$ , versus pulse width  $t_p$ , for sinusoidal currents,  $t_p \le 20ms$ .



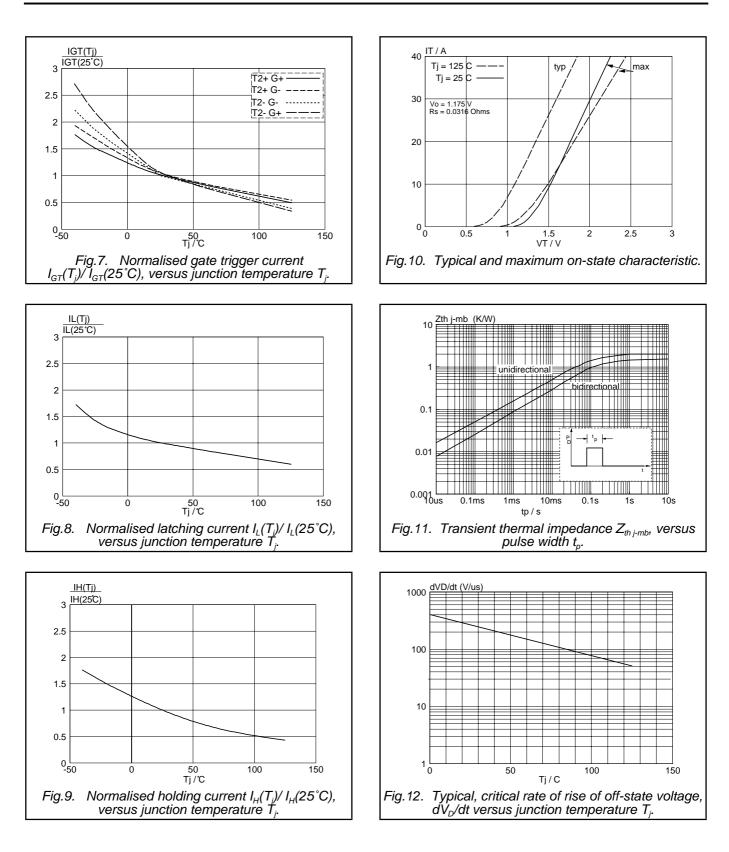






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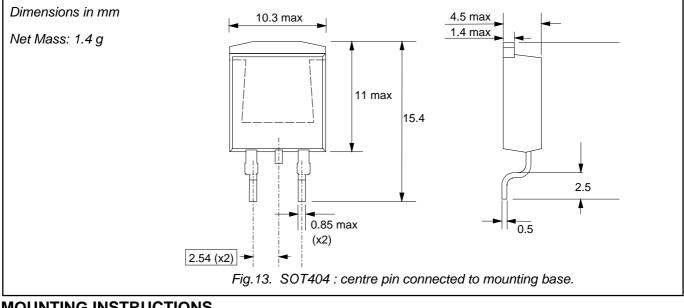
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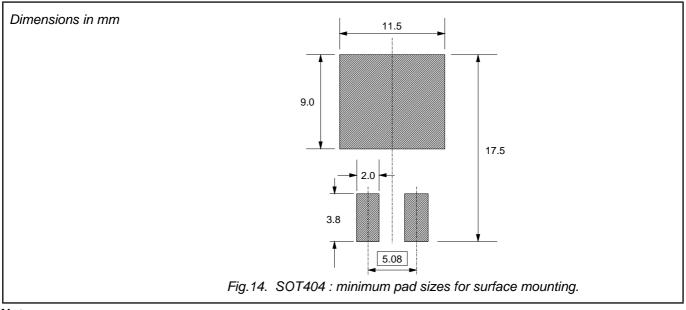
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# **MECHANICAL DATA**



# **MOUNTING INSTRUCTIONS**



#### Notes

1. Plastic meets UL94 V0 at 1/8".

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#### DEFINITIONS

DATA SHEET STATUS					
DATA SHEET PRODUCT STATUS <sup>2</sup> STATUS <sup>3</sup>		DEFINITIONS			
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice			
Supplementary dat Semiconductors re		This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in ordere to improve the design and supply the best possible product			
Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Changes will be communicated according to the Customer Product/Process Change Notification (CPCN) procedure SNW-SQ-650A			

#### Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

#### Application information

Where application information is given, it is advisory and does not form part of the specification.

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